

RELIABILITY REPORT
FOR
MAX4233AUB+
PLASTIC ENCAPSULATED DEVICES

September 25, 2009

MAXIM INTEGRATED PRODUCTS

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Approved by
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Conclusion

The MAX4233AUB+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX4230-MAX4234 single/dual/quad, high-output-drive CMOS op amps feature 200mA of peak output current, rail-to-rail input, and output capability from single 2.7V to 5.5V supply. These amplifiers exhibit high slew rate of 10V/ μ s and a gain-bandwidth product (GBWP) of 10MHz. The MAX4230-MAX4234 can drive typical headset levels (32), as well as bias an RF power amplifier (PA) in wireless handset applications. The MAX4230 comes in a tiny 5-pin SC70 package and the MAX4231, single with shutdown, is offered in the 6-pin SC70 package and a 1.5mm x 1.0mm x 0.5mm ultra-thin μ DFN package. The dual op-amp MAX4233 offered in the space-saving 10-bump chip-scale package (UCSP(tm)), providing the smallest footprint area for a dual op amp with shutdown. These op amps are designed to be part of the PA control circuitry, biasing RF PAs in wireless headsets. The MAX4231/MAX4233 offer a active-low SHDN feature that drives the output low. This ensures that the RF PA is fully disabled when needed, preventing unconverted signals to the RF antenna. The MAX4230 family offers low offsets, wide bandwidth, and high-output drive in a tiny 2.1mm x 2.0mm space-saving SC70 package. These parts are offered over the automotive temperature range (-40°C to +125°C).

II. Manufacturing Information

A. Description/Function:	High-Output-Drive, 10MHz, 10V/ μ s, Rail-to-Rail I/O Op Amps with Shutdown in SC70
B. Process:	VS50
C. Number of Device Transistors:	
D. Fabrication Location:	Taiwan
E. Assembly Location:	
F. Date of Initial Production:	October 27, 2001

III. Packaging Information

A. Package Type:	10-pin uMAX
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive Epoxy
E. Bondwire:	Gold (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-2849
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	180°C/W
K. Single Layer Theta Jc:	41.9°C/W
L. Multi Layer Theta Ja:	113.1°C/W
M. Multi Layer Theta Jc:	41.9°C/W

IV. Die Information

A. Dimensions:	45 X 41 mils
B. Passivation:	Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	0.50 μ m
F. Minimum Metal Spacing:	0.50 μ m
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

- A. Quality Assurance Contacts: Ken Wendel (Director, Reliability Engineering)
Bryan Preeshl (Managing Director of QA)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 124 \times 2} \text{ (Chi square value for MTTF upper limit)}$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 8.7 \times 10^{-9}$$

$\lambda = 8.7$ F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maxim-ic.com/qa/reliability/monitor>. Cumulative monitor data for the VS50 Process results in a FIT Rate of 0.72 @ 25C and 12.47 @ 55C (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

C. E.S.D. and Latch-Up Testing

The OX77 die type has been found to have all pins able to withstand a HBM transient pulse of +/-1500 per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-250 mA.

Table 1
Reliability Evaluation Test Results

MAX4233AUB+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test (Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality	124	0
Moisture Testing (Note 2)				
HAST	Ta = 130°C RH = 85% Biased Time = 96hrs.	DC Parameters & functionality	77	0
Mechanical Stress (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality	77	0

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data